

Solid State Relay OCMOS FET PS7212-1A

# 4-PIN SOP 100 V BREAK DOWN VOLTAGE 1-ch Optical Coupled MOS FET

### DESCRIPTION

The PS7212-1A is a solid state relay containing GaAs LEDs on the light emitting side (input side) and normally open (N.O.) contact MOS FETs on the output side.

It is suitable for analog signal control because of its low offset and high linearity.

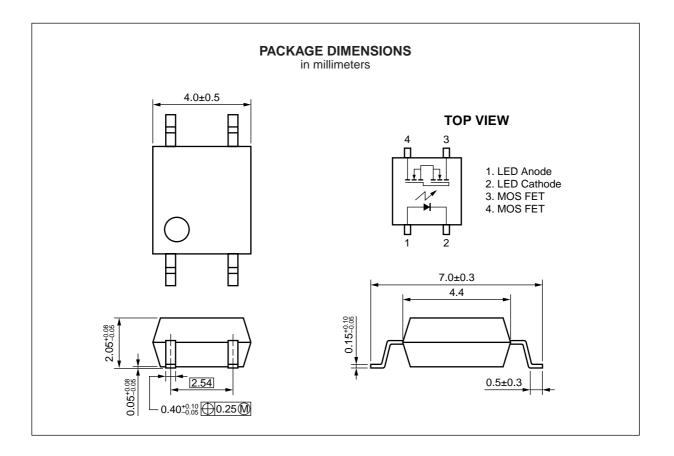
### FEATURES

- Small and thin package (4-pin SOP, Height = 2.1 mm)
- 1 channel type (1 a output)
- Low LED operating current (IF = 2 mA)
- Designed for AC/DC switching line changer
- Low offset voltage
- Ordering number of taping product: PS7212-1A-E3, E4, F3, F4

### APPLICATIONS

- Laptop PC, PDA
- Modem card
- Telephone, FAX
- Measurement equipment

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### ★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number <sup>*1</sup>
PS7212-1A	4-pin SOP	Magazine case 100 pcs	PS7212-1A
PS7212-1A -E3		Embossed Tape 900 pcs/reel	
PS7212-1A -E4			
PS7212-1A -F3		Embossed Tape 3 500 pcs/reel	
PS7212-1A -F4			

\*1 For the application of the Safety Standard, following part number should be used.

## ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	lF	50	mA	
	Reverse Voltage	VR	5.0	V	
	Power Dissipation		50	mW	
	Peak Forward Current <sup>*1</sup>	<b>I</b> FP	1	А	
MOS FET	IOS FET Break Down Voltage		100	V	
	Continuous Load Current	١L	200	mA	
	Pulse Load Current <sup>*2</sup> (AC/DC Connection)	Ilp	400	mA	
	Power Dissipation	PD	300	mW	
Isolation Voltage <sup>*3</sup>		BV	1 500	Vr.m.s.	
Total Power Dissipation		Рт	350	mW	
Operating Ambient Temperature		TA	-40 to +80	°C	
Storage Temperature		Tstg	-40 to +100	°C	

\*1 PW = 100  $\mu$ s, Duty Cycle = 1 %

\*2 PW = 100 ms, 1 shot

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\*3 AC voltage for 1 minute at TA = 25 °C, RH = 60 % between input and output

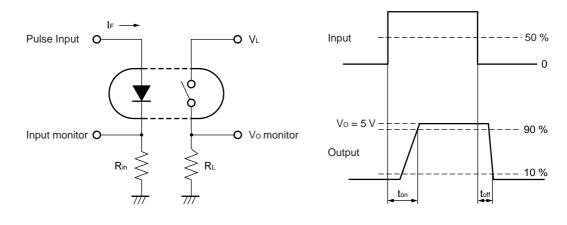
## **RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)**

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

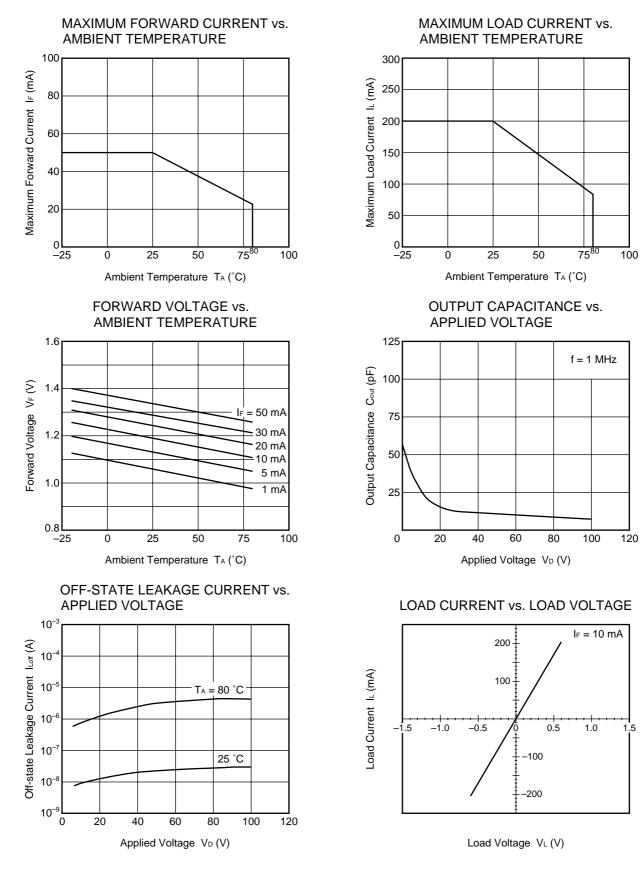
# ELECTRICAL CHARACTERISTICS (TA = 25 °C)

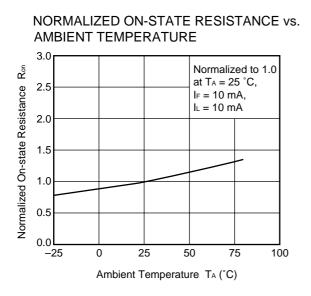
		Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
	Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
		Reverse Current	IR	V <sub>R</sub> = 5 V			5.0	μA
*	MOS FET	Off-state Leakage Current	Loff	V <sub>D</sub> = 100 V		0.03	1.0	μA
		Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		57		pF
	Coupled	LED On-state Current	Fon	I∟ = 200 mA			2.0	mA
		On-state Resistance	Ron1	IF = 10 mA, IL = 10 mA		3.0	6.0	Ω
*			Ron2	$I_F$ = 10 mA, $I_L$ = 200 mA, $t \le$ 10 ms				
		Turn-on Time <sup>*1</sup>	ton	$I_F$ = 10 mA, Vo = 5 V, PW $\geq$ 10 ms		0.35	1.0	ms
		Turn-off Time <sup>*1</sup>	toff			0.08	0.2	
		Isolation Resistance	Ri-o	VI-O = 1.0 kVDC	10°			Ω
		Isolation Capacitance	CI-O	V = 0 V, f = 1 MHz		0.5		pF

\* \*1 Test Circuit for Switching Time

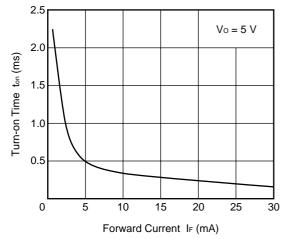


### ★ TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise specified)

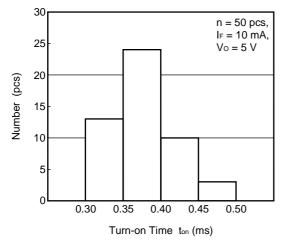




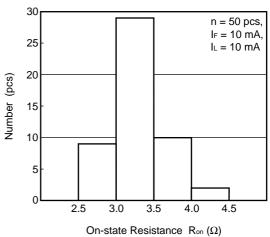




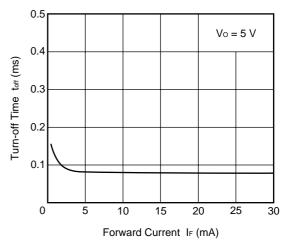
### TURN-ON TIME DISTRIBUTION



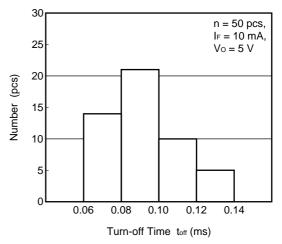
**ON-STATE RESISTANCE DISTRIBUTION** 

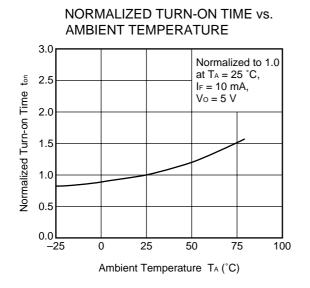


TURN-OFF TIME vs. FORWARD CURRENT

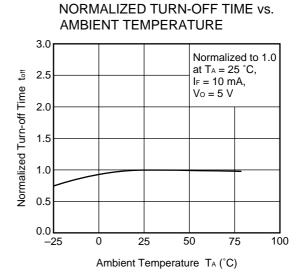


#### TURN-OFF TIME DISTRIBUTION

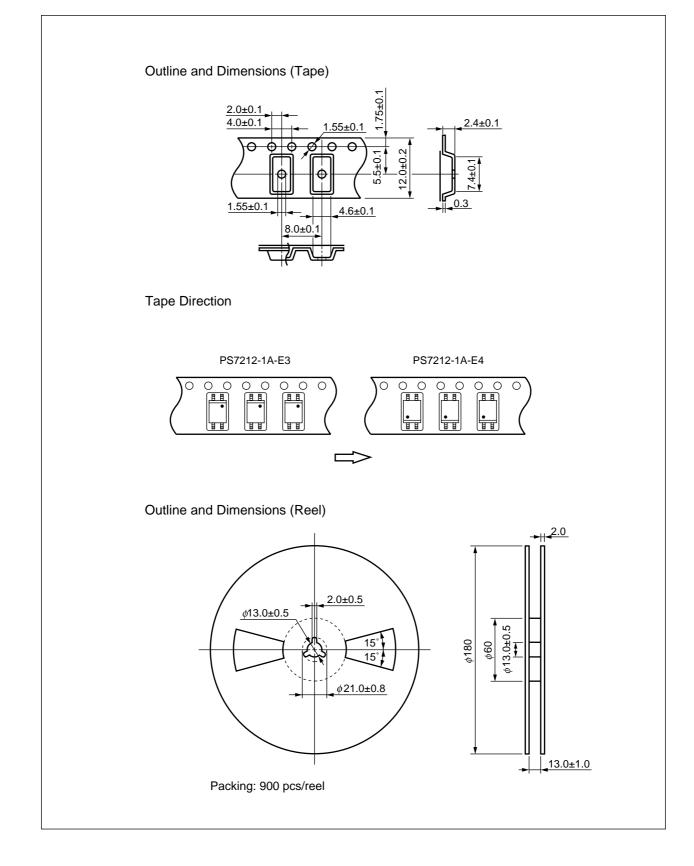


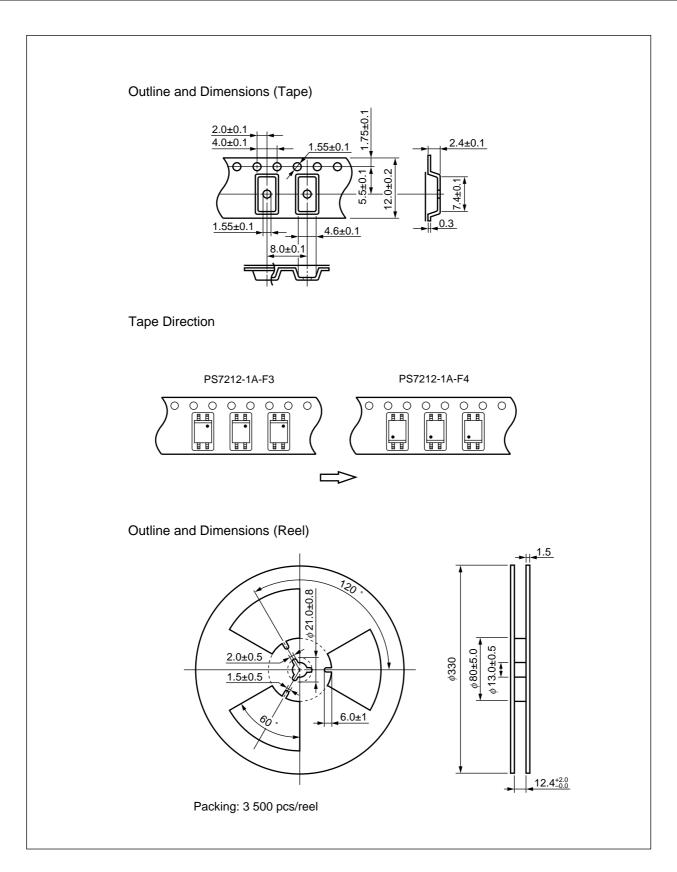


Remark The graphs indicate nominal characteristics.



### \* TAPING SPECIFICATIONS (in millimeters)





## **\*** RECOMMENDED SOLDERING CONDITIONS

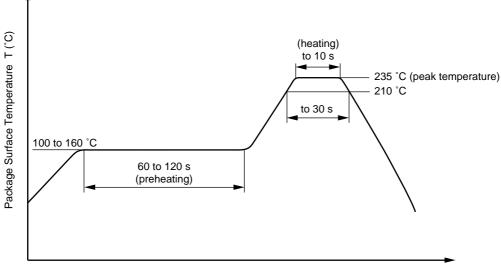
### (1) Infrared reflow soldering

- Peak reflow temperature
  235 °C (package surface temperature)
- Time of temperature higher than 210 °C
- Number of reflows
- Flux

Two Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

### Recommended Temperature Profile of Infrared Reflow

30 seconds or less





### (2) Dip soldering

### • Temperature 260 °C or below (molten solder temperature)

- Time
- 10 seconds or less
- Number of times One
- Flux

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

### (3) Cautions

• Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

## CAUTION

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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